

RJH60D1DPP-E0

600V - 10A - IGBT

Application: Inverter

R07DS0893EJ0100

Rev.1.00

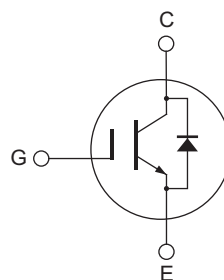
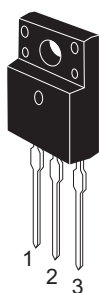
Nov 01, 2012

Features

- Short circuit withstand time (5 μ s typ.)
- Low collector to emitter saturation voltage
 $V_{CE(sat)} = 1.9$ V typ. (at $I_C = 10$ A, $V_{GE} = 15$ V, $T_a = 25^\circ\text{C}$)
- Built in fast recovery diode (70 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching
 $t_f = 75$ ns typ. (at $V_{CC} = 300$ V, $V_{GE} = 15$ V, $I_C = 10$ A, $R_g = 5 \Omega$, inductive load)

Outline

RENESAS Package code: PRSS0003AG-A
 (Package name: TO-220FP)



1. Gate
2. Collector
3. Emitter

Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

| Item | Symbol | Ratings | Unit |
|--|----------------------------------|-------------|-----------------------------|
| Collector to emitter voltage / diode reverse voltage | V_{CES} / V_R | 600 | V |
| Gate to emitter voltage | V_{GES} | ± 30 | V |
| Collector current | $T_c = 25^\circ\text{C}$ | I_C | A |
| | $T_c = 100^\circ\text{C}$ | I_C | A |
| Collector peak current | $i_{c(peak)}$ ^{Note1} | 40 | A |
| Collector to emitter diode forward current | i_{DF} | 10 | A |
| Collector to emitter diode forward peak current | $i_{D(peak)}$ ^{Note1} | 40 | A |
| Collector dissipation | P_C ^{Note2} | 30 | W |
| Junction to case thermal resistance (IGBT) | θ_{j-c} ^{Note2} | 4.1 | $^\circ\text{C} / \text{W}$ |
| Junction to case thermal resistance (Diode) | θ_{j-cd} ^{Note2} | 7.2 | $^\circ\text{C} / \text{W}$ |
| Junction temperature | T_j | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |

Notes: 1. $PW \leq 10 \mu\text{s}$, duty cycle $\leq 1\%$

2. Value at $T_c = 25^\circ\text{C}$

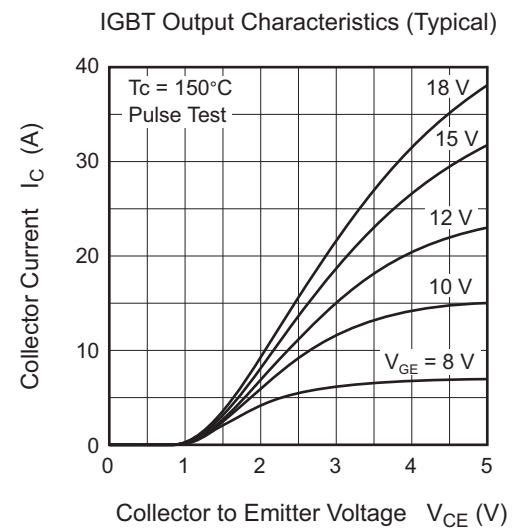
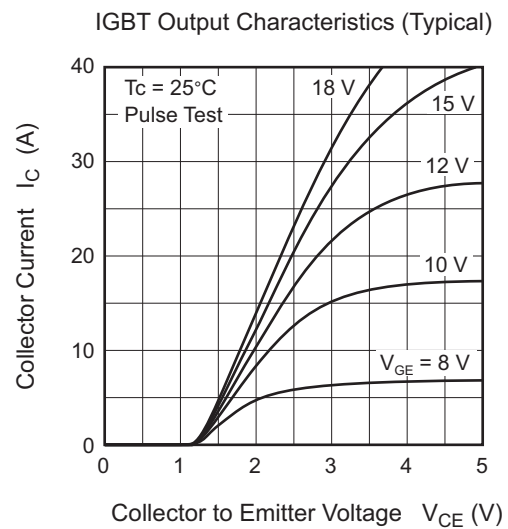
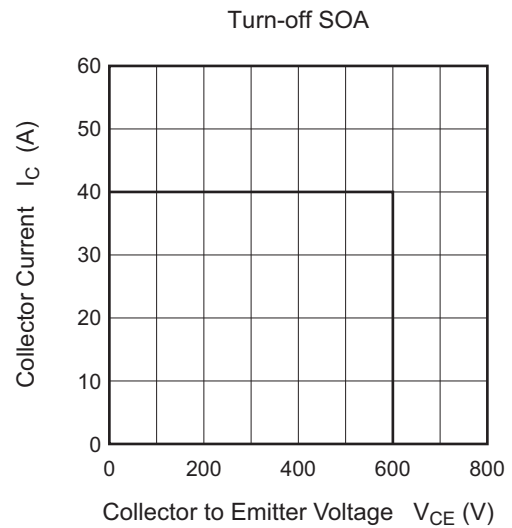
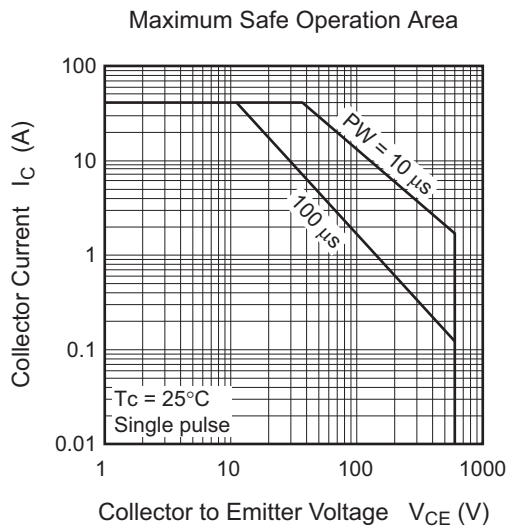
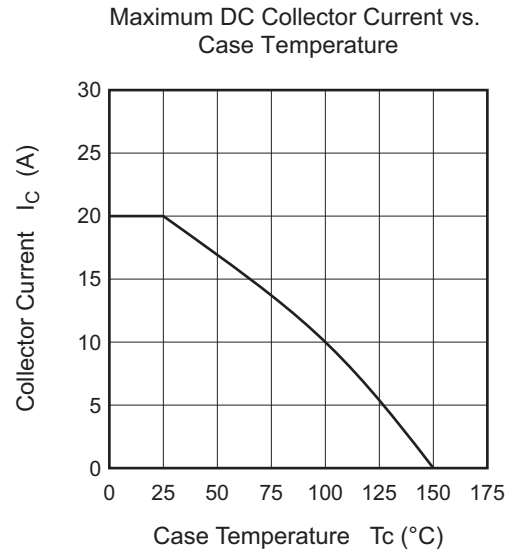
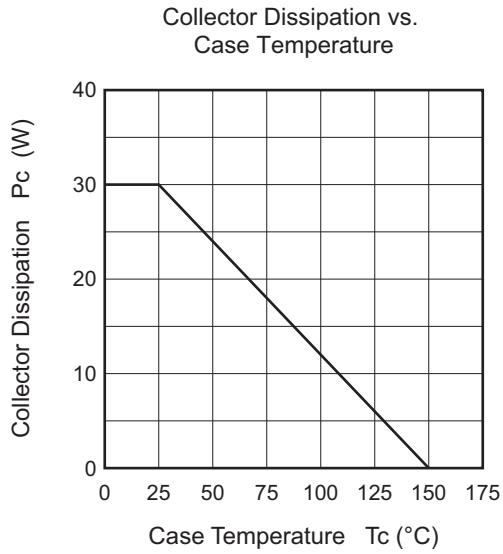
Electrical Characteristics

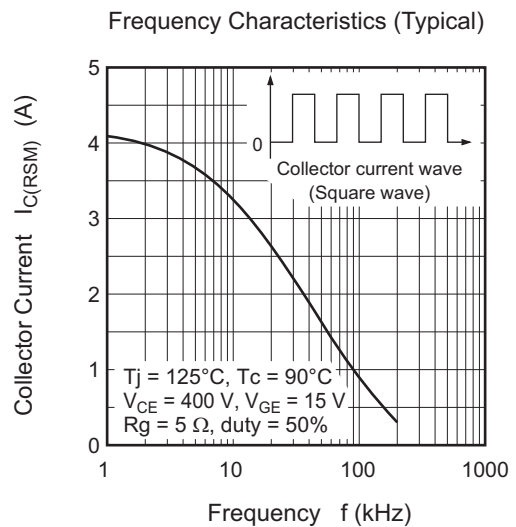
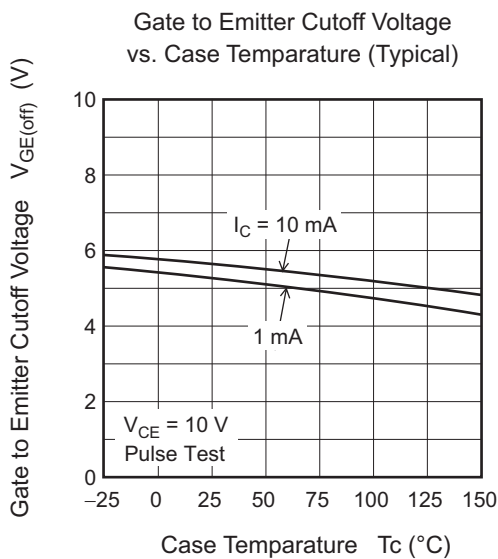
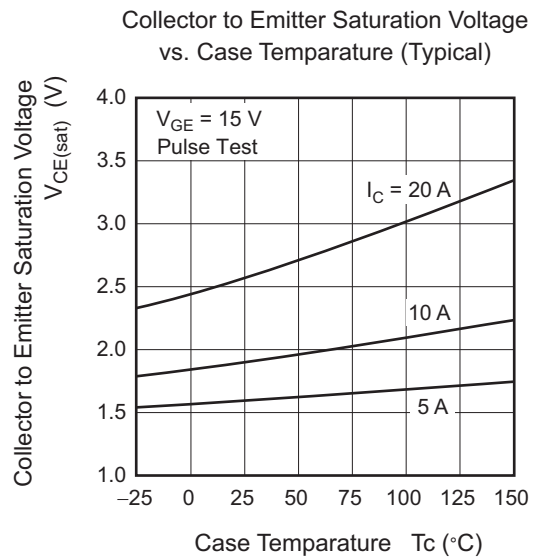
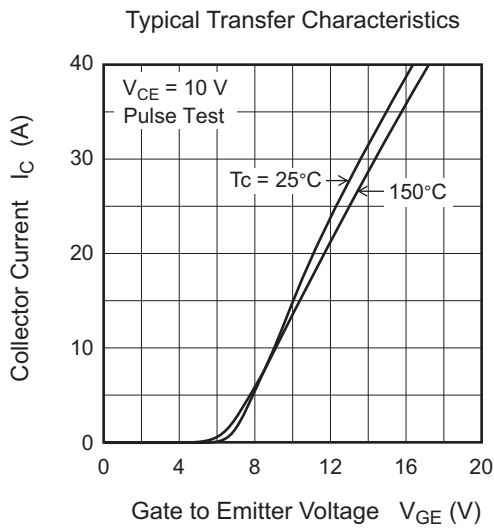
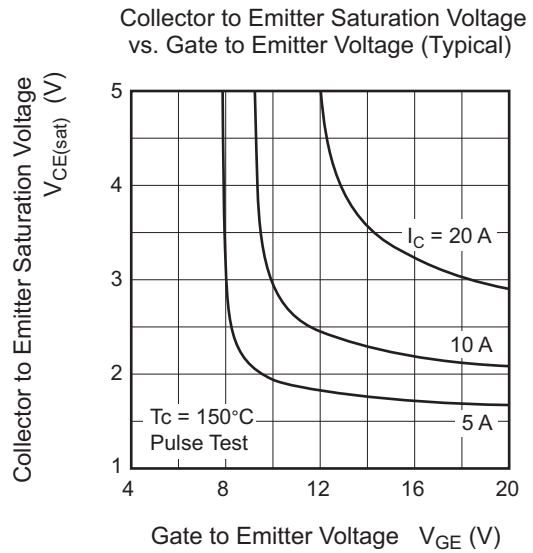
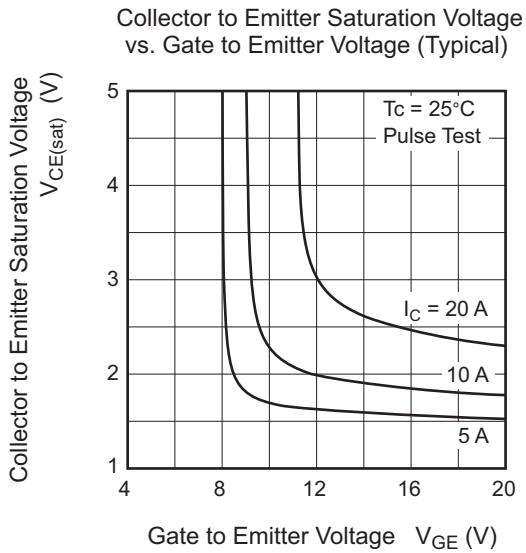
(Ta = 25°C)

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions |
|---|-----------------|-----|------|---------|---------|--|
| Collector to emitter breakdown voltage | $V_{BR(CES)}$ | 600 | — | — | V | $I_C = 10 \mu A, V_{GE} = 0$ |
| Zero gate voltage collector current / Diode reverse current | I_{CES} / I_R | — | — | 5 | μA | $V_{CE} = 600 V, V_{GE} = 0$ |
| Gate to emitter leak current | I_{GES} | — | — | ± 1 | μA | $V_{GE} = \pm 30 V, V_{CE} = 0$ |
| Gate to emitter cutoff voltage | $V_{GE(off)}$ | 4.0 | — | 6.0 | V | $V_{CE} = 10 V, I_C = 1 mA$ |
| Collector to emitter saturation voltage | $V_{CE(sat)}$ | — | 1.9 | 2.5 | V | $I_C = 10 A, V_{GE} = 15 V$ ^{Note3} |
| | $V_{CE(sat)}$ | — | 2.6 | — | V | $I_C = 20 A, V_{GE} = 15 V$ ^{Note3} |
| Input capacitance | C_{ies} | — | 275 | — | pF | $V_{CE} = 25 V$ |
| Output capacitance | C_{oes} | — | 25 | — | pF | $V_{GE} = 0$ |
| Reveres transfer capacitance | C_{res} | — | 8 | — | pF | $f = 1 MHz$ |
| Total gate charge | Q_g | — | 13 | — | nC | $V_{GE} = 15 V$ |
| Gate to emitter charge | Q_{ge} | — | 3 | — | nC | $V_{CE} = 300 V$ |
| Gate to collector charge | Q_{gc} | — | 5 | — | nC | $I_C = 10 A$ |
| Turn-on delay time | $t_{d(on)}$ | — | 30 | — | ns | $V_{CC} = 300 V$ |
| Rise time | t_r | — | 13 | — | ns | $V_{GE} = 15 V$ |
| Turn-off delay time | $t_{d(off)}$ | — | 42 | — | ns | $I_C = 10 A$ |
| Fall time | t_f | — | 75 | — | ns | $R_g = 5 \Omega$ |
| Turn-on energy | E_{on} | — | 0.10 | — | mJ | (Inductive load) |
| Turn-off energy | E_{off} | — | 0.13 | — | mJ | |
| Total switching energy | E_{total} | — | 0.23 | — | mJ | |
| Short circuit withstand time | t_{sc} | 3.0 | 5.0 | — | μs | $V_{GE} \leq 360 V, V_{GE} = 15 V$ |
| FRD forward voltage | V_F | — | 1.4 | 1.9 | V | $I_F = 10 A$ ^{Note3} |
| FRD reverse recovery time | t_{rr} | — | 70 | — | ns | $I_F = 10 A$ |
| FRD reverse recovery charge | Q_{rr} | — | 0.11 | — | μC | $di_F/dt = 100 A/\mu s$ |
| FRD peak reverse recovery current | I_{rr} | — | 3.5 | — | A | |

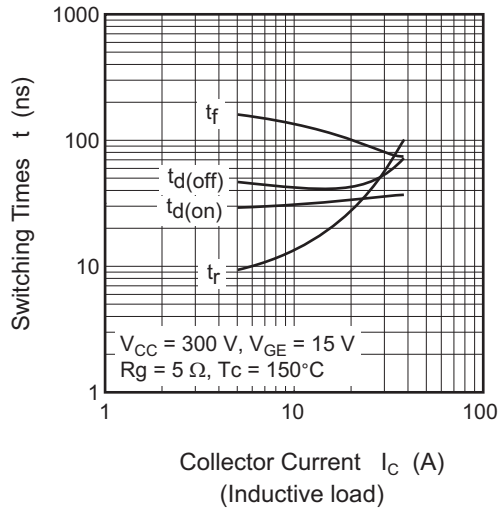
Notes: 3. Pulse test.

Main Characteristics

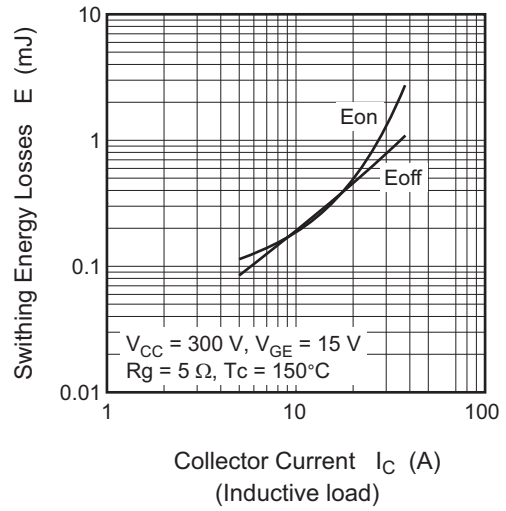




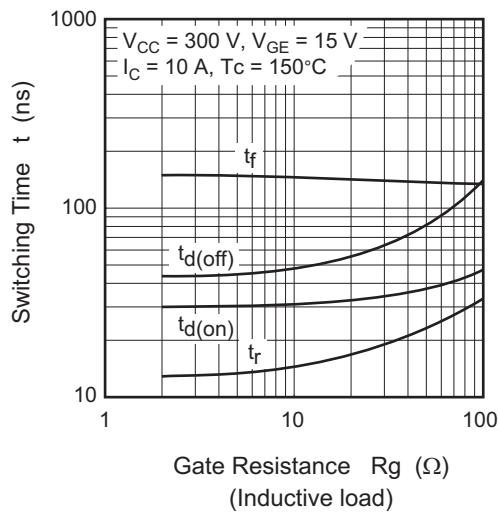
Switching Characteristics (Typical) (1)



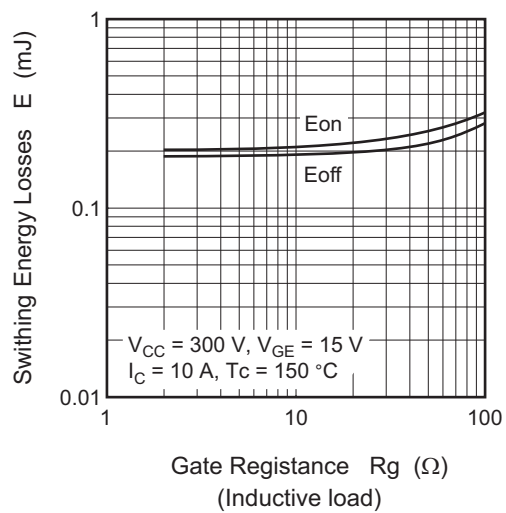
Switching Characteristics (Typical) (2)



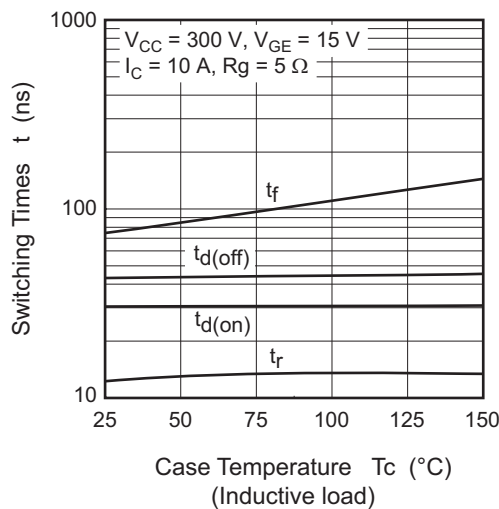
Switching Characteristics (Typical) (3)



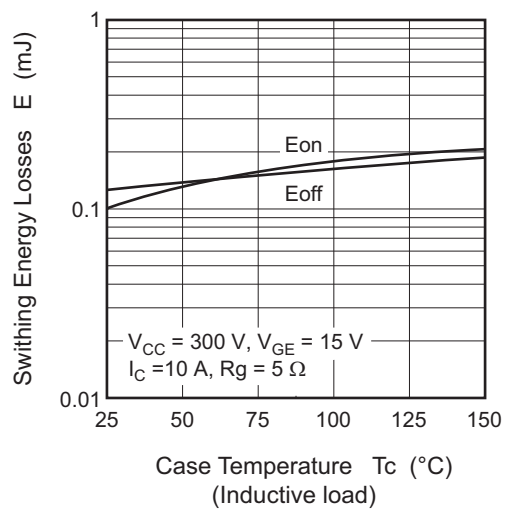
Switching Characteristics (Typical) (4)



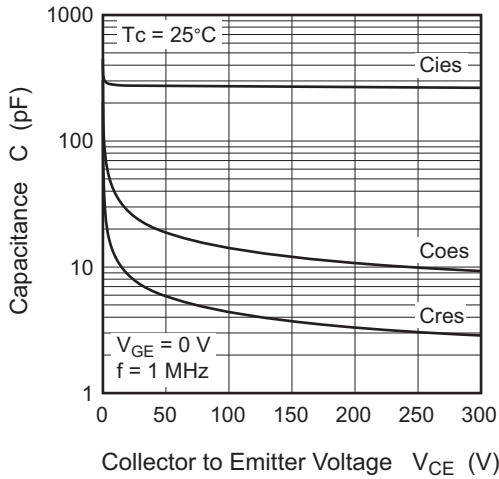
Switching Characteristics (Typical) (5)



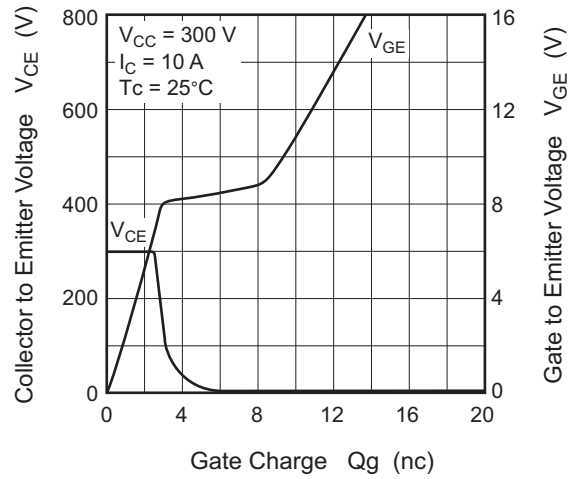
Switching Characteristics (Typical) (6)



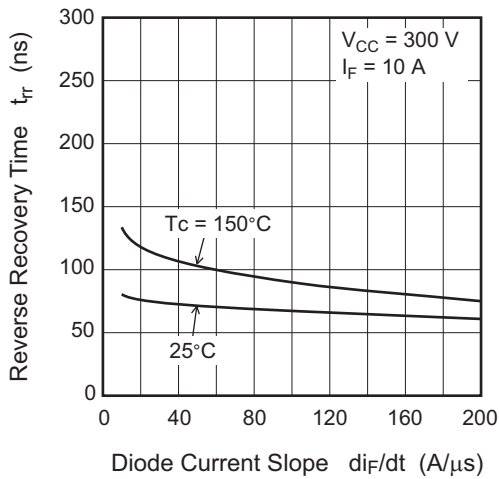
Typical Capacitance vs. Collector to Emitter Voltage



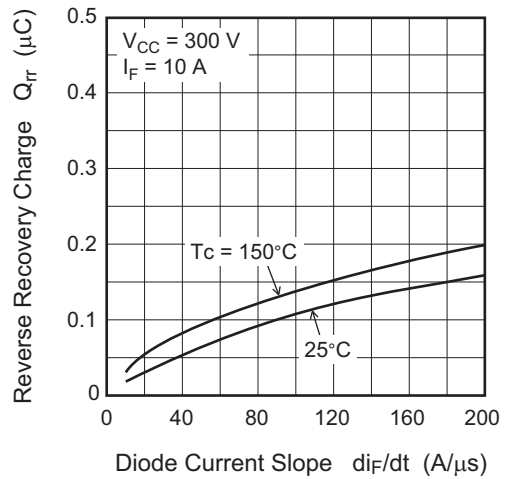
Dynamic Input Characteristics (Typical)



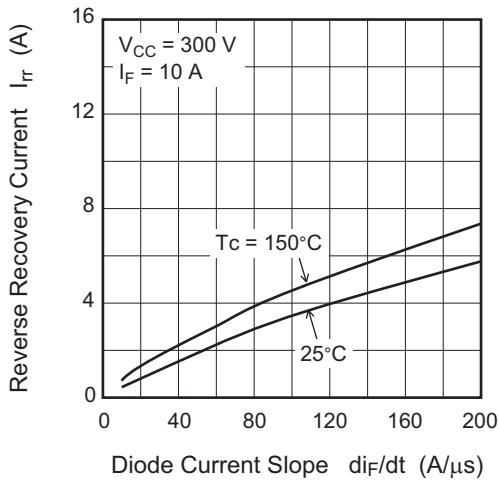
Reverse Recovery Time vs. Diode Current Slope (Typical)



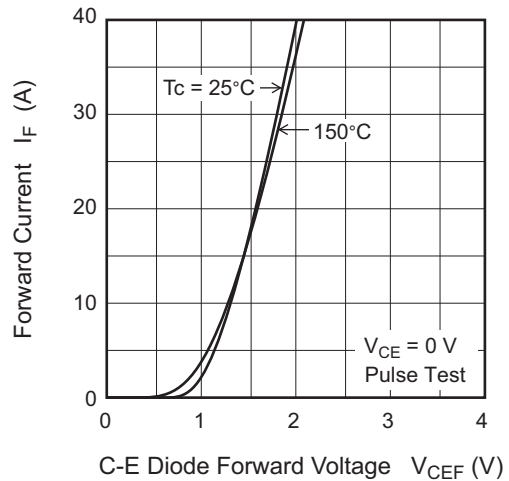
Reverse Recovery Charge vs. Diode Current Slope (Typical)

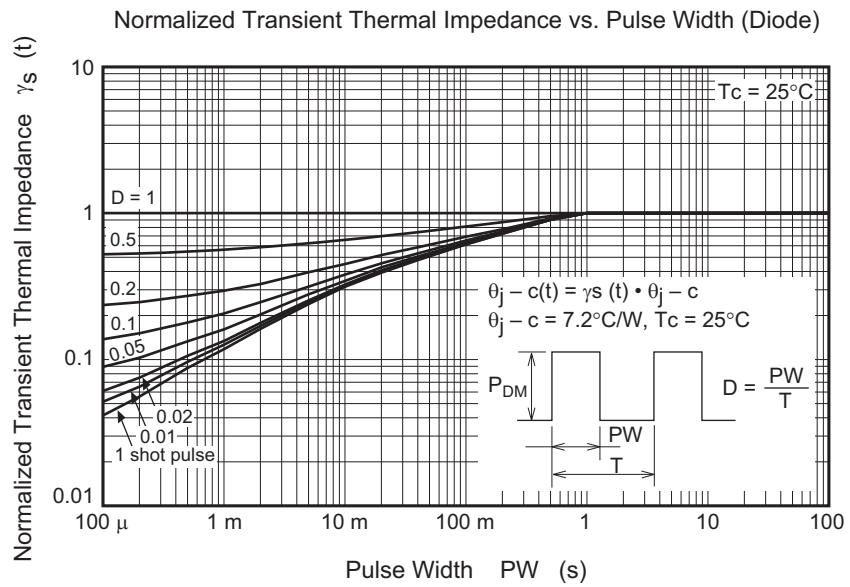
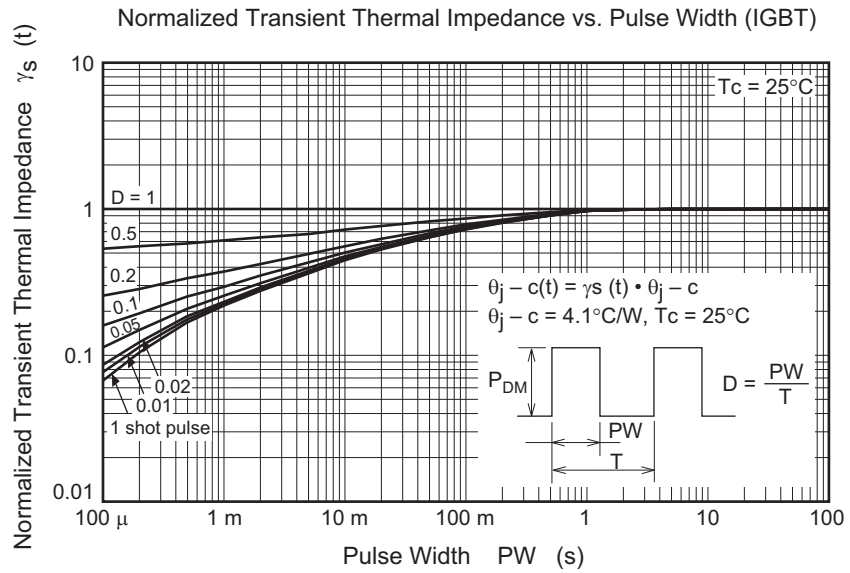


Reverse Recovery Current vs. Diode Current Slope (Typical)

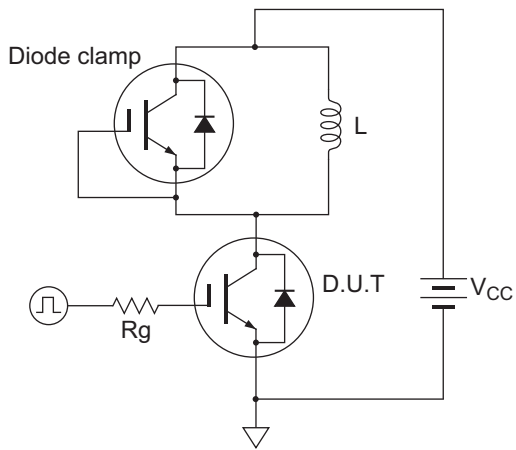


Forward Current vs. Forward Voltage (Typical)

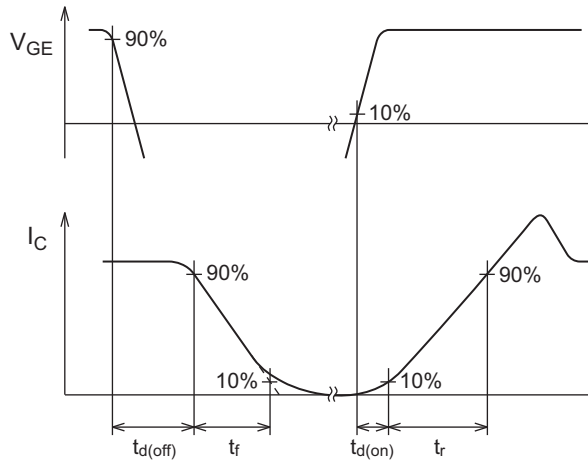




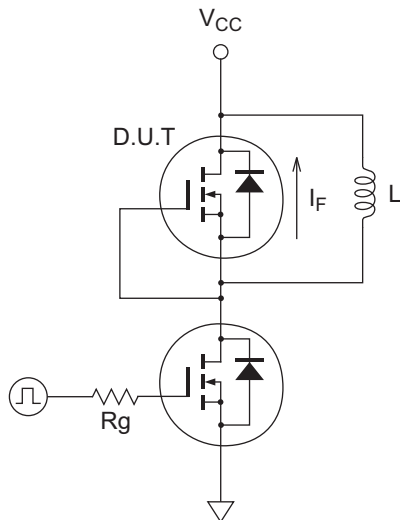
Switching Time Test Circuit



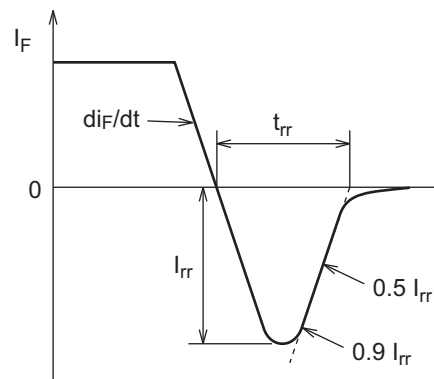
Waveform



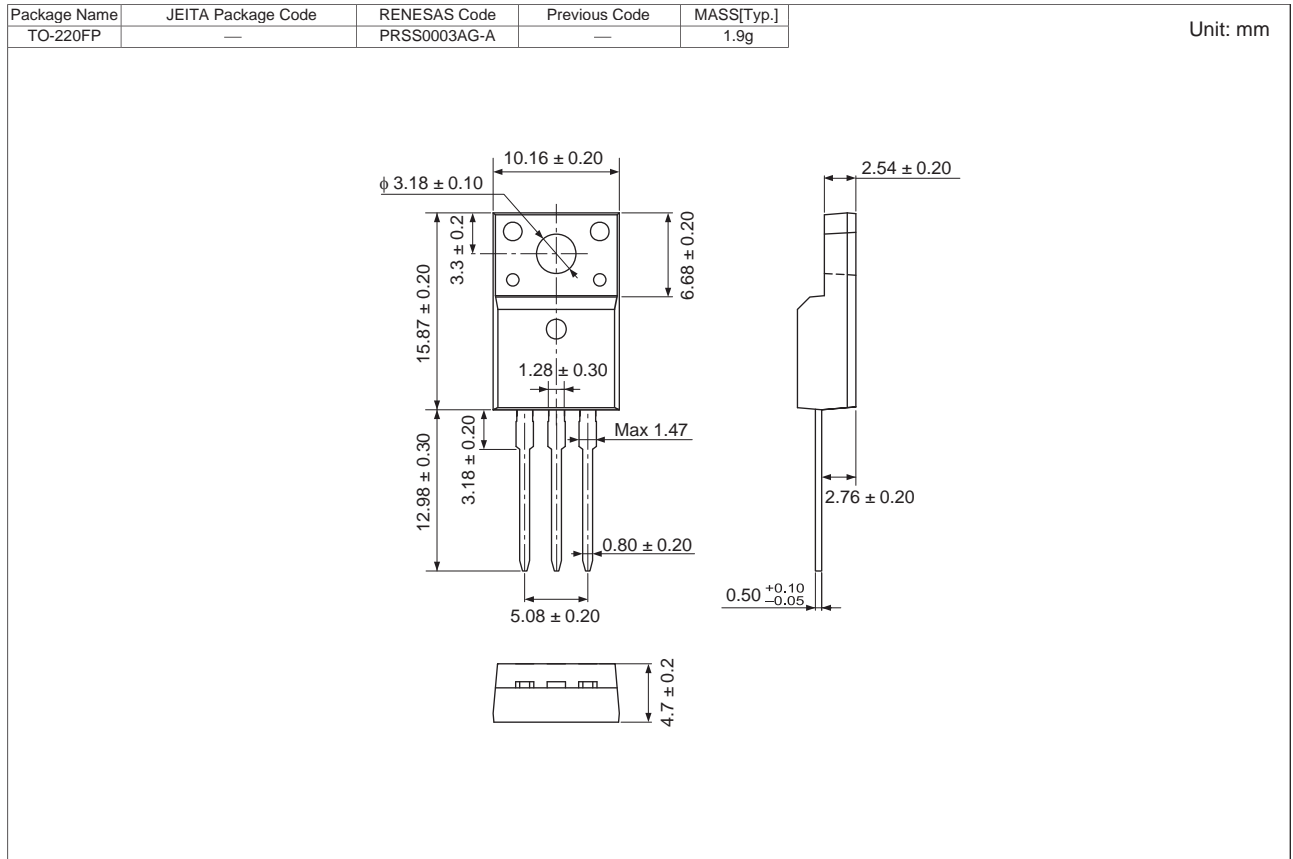
Diode Reverse Recovery Time Test Circuit



Waveform



Package Dimension



Ordering Information

| Orderable Part Number | Quantity | Shipping Container |
|-----------------------|----------|--------------------|
| RJH60D1DPP-E0#T2 | 1000 pcs | Box (Tube) |

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Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited
1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada
Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China
Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
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